

0.37 Ω , Low THD and Capacitance, Dual DPDT / Quad SPDT Analog Switch

DESCRIPTION

The DG2525, is a four-channel single-pole double-throw (SPDT) analog switch with two control inputs. It is also known as a two-channel double-pole double-throw (DPDT) configuration. The part is designed to operate from 1.8 V to 5.5 V single power rail. All switches conduct equally well in both directions, offering rail to rail signal witching and can be used both as multiplexers as well as de-multiplexers.

The DG2525 offers low leakage, parasitic capacitance, and highly matched low and flat switch resistance over the full signal range. It features break-before-make switching and low control logic threshold. The part exhibits high bandwidth and excellent total harmonic distortion (THD). It is ideal for both analog and digital signal switching in space constrain applications requiring high performance and efficient use of board space.

The DG2525 comes in a small miniQFN-16 lead package of 2.6 mm x 1.8 mm x 0.55 mm.

BENEFITS

- · Low and flat resistance
- · Excellent total harmonic distortion
- · Low leakage and parasitic capacitance
- Low voltage control interface

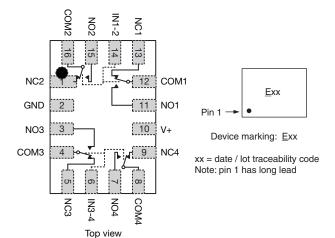
FEATURES

- 1.8 V to 5.5 V single supply operation
- Low resistance: 0.4 Ω/typ. at 2.7 V
- Highly flat and matched R_{ON}
- Low parasitic capacitance,
 C_{ON} = 26 pF, C_{OFF} = 14.5 pF
- Switch off leakage: 5 pA at V+ = 3.3 V, 40 pA at V+ = 5.5 V
- High bandwidth: 310 MHz
- -100 dB THD + N at 1 kHz, 0.9 V_{RMS} , R_{LOAD} = 32 Ω
- Guaranteed logic high 1.2 V, logic low 0.3 V
- Break before make switching
- Signal swing over V+ capable
- Power down protection
- Latch up current: 300 mA (JESD78)
- ESD / HBM: > 6 kV
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

APPLICATIONS

- Smart phones and tablets
- Portable instrumentation
- · Audio and video signal switching
- · Modems and peripherals
- · Data storage
- Wireless pins
- · Relay replacement

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE			
LOGIC	NC1, 2, 3, and 4	NO1, 2, 3, and 4	
0	On	Off	
1	Off	On	



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ORDERING INFORMATION					
TEMPERATURE RANGE	PACKAGE	PART NUMBER	MIN. ORDER / PACK. QUANTITY		
-40 °C to +85 °C lead (Pb)-free	miniQFN-16	DG2525DN-T1-GE4	Tape and reel, 3000 units		

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Reference to GND	V+		-0.3 to +6	V	
	IN, COM, NC, NO a		-0.3 to (V+ + 0.3)	¬	
Current (any terminal except NO, NC, or COM)			30		
Continuous current (NO, NC, or COM)			± 300	mA	
Peak current (pulsed at 1 ms, 10 % duty cycle)			± 500		
Storage temperature (D suffix)			-65 to +150	°C	
Package solder reflow conditions d	miniQFN-16		250		
Power dissipation (packages) b	miniQFN-16 ^c		525	mW	

Notes

- a. Signals on NC, NO, or COM, or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 6.6 mW/°C above 70 °C.
- d. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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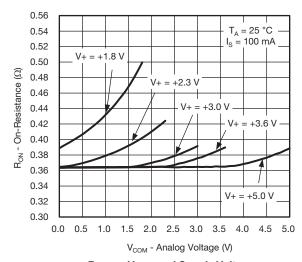
SPECIFICATIONS (V+ = 3 V)							
PARAMETER	SYMBOL	TEST CONDITIONS unless otherwise specified V+ = 3 V, \pm 10 %, V_{IN} = 0.5 or 1.4 V $^{\rm e}$	TEMP.a	LIMITS -40 °C to +85 °C			UNIT
				MIN. b	TYP. c	MAX. b	
Analog Switch							
Analog signal range ^d	V_{NO}, V_{NC}, V_{COM}		Full	0	-	V+	٧
On-resistance	R _{ON}	V+ = 2.7 V, V_{COM} = 0 to 2.7 V, I_{NO} , I_{NC} = 100 mA	Room	-	0.37	0.5	Ω
On resistance		V+ = 2.7 V, V _{COM} = 0 to V+,	Full	-	-	0.6	
R _{ON} flatness ^d	R _{ON} flatness		Full	-	0.03	0.08	
R _{ON} match ^d	ΔR_{ON}	I_{NO} , $I_{NC} = 100 \text{ mA}$	Room	-	0.05	-	
	I _{NO(off)} ,		Room	-1	0.04	1	
Switch off leakage current	I _{NC(off)}	$V+ = 5.5 V, V_{NO}, V_{NC} = 0.5 V / 4 V,$	Full	-5	-	5	
Switch on leakage current		$V_{COM} = 4 \text{ V} / 0.5 \text{ V}$	Room	-1	0.17	1	~ Λ
	I _{COM(off)}		Full	-5	-	5	nA
Channel-on leakage		V. 55V.V. V. 05V./4V	Room	-1	0.17	1	
current	ICOM(on)	$V+ = 5.5 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 0.5 \text{ V} / 4 \text{ V}$	Full	-5	-	5	
Digital Control						•	
Input high voltage	V _{INH}		- "	1.2	-	-	
Input low voltage	V _{INL}		Full	-	-	0.3	V
Input capacitance	C _{IN}		Full	-	5	-	pF
Input current	I _{INL} or I _{INH}	V _{IN} = 0 or V+	Full	-1	-	1	μA
Dynamic Characteristics			L	L	L	1	
÷			Room	-	38	60	μs
Turn-on time	t _{ON}	V_{NO} or V_{NC} = 1.5 V, R_L = 50 Ω , C_L = 35 pF	Full	-	-	70	
			Room	-	0.43	1	
Turn-off time			Full	-	-	3	
Break-before-make time	t _d		Full	1	-	-	
Charge injection d	Q _{INJ}	$C_L = 1 \text{ nF}, V_{GEN} = 1.5 \text{ V}, R_{GEN} = 0 \Omega$	Room	-	-19	-	рС
-3 dB bandwidth	BW	$R_L = 50 \Omega$, $C_L = 5 pF$	Room	-	310	-	MHz
Off-isolation ^d		$R_L = 50 \Omega, C_L = 5 pF, f = 100 kHz$	Room	-	-82	-	dB
	OIRR	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$		_	-55	-	
Crosstalk d, f		R _L = 50 Ω, C _L = 5 pF, f = 100 kHz		-	-89	-	
	X _{TALK}	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$		-	-61	-	
Total harmonic distortion plus noise	THD + N	2.5 V, signal peak to peak voltage $R_L = 32 \Omega$, f = 1 kHz		-	-100	-	
No No # " '	C _{NO(off)}	f = 1 MHz		-	14.5	-	
NO, NC off capacitance ^d Channel-on capacitance ^d	C _{NC(off)}		Room	-	14.5	-	pF
	C _{NO(on)}			-	26	-	
	C _{NC(on)}			-	26	-	
Power Supply	1.5(61)		<u> </u>	<u> </u>		l	
Power supply range	V+			1.8	_	5.5	V
Power supply current	I+	V _{IN} = 0 or V+	Full	-	29	60	μA
Jupp.j Junioni		-1114 3 01 4 1		l			۳,,

Notes

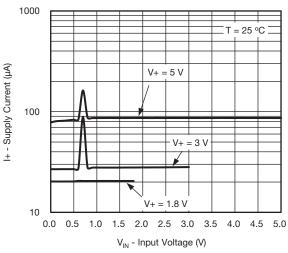
- a. Room = 25 $^{\circ}$ C, full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, not subjected to production test.
- e. V_{IN} = input voltage to perform proper function.
- f. Crosstalk measured between channels.



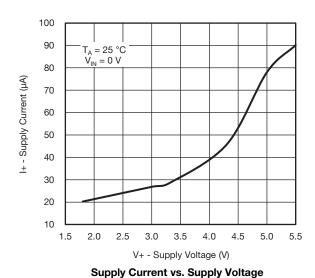
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



R_{ON} vs. V_{COM} and Supply Voltage

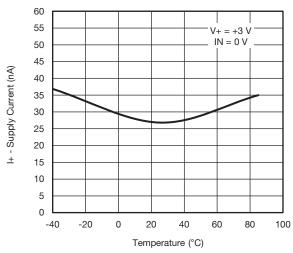


Supply Current vs. Input Voltage

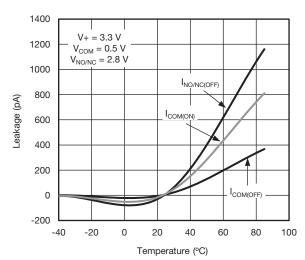


0.54 0.52 V + = +3.0 V0.50 I_S = 100 mA +85 °C 0.48 0.46 On-Resistance (Ω) 0.44 0.42 +25 °C 0.40 0.38 0.36 0.34 40 °C 0.32 0.30 0.28 0.26 0.24 0.22 0.20 0.0 0.5 1.0 3.0 V_{COM} - Analog Voltage (V)

R_{ON} vs. Analog Voltage and Temperature



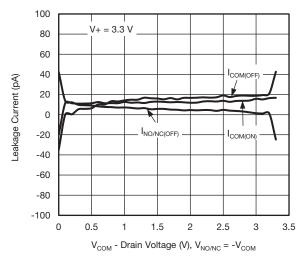
Supply Current vs. Temperature



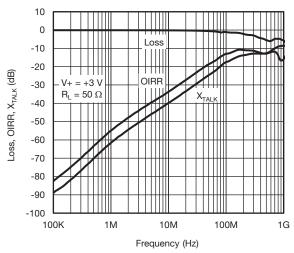
Leakage Current vs. Temperature



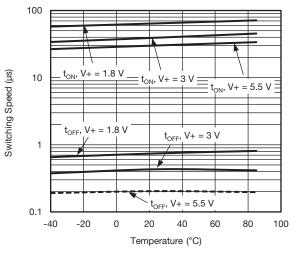
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



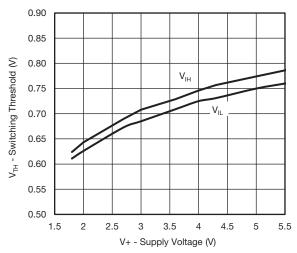
Leakage Current vs. Drain Voltage



Insertion Loss, Off-Isolation Crosstalk vs. Frequency



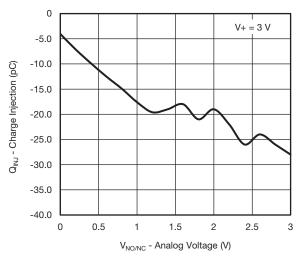
Switching Time vs. Temperature



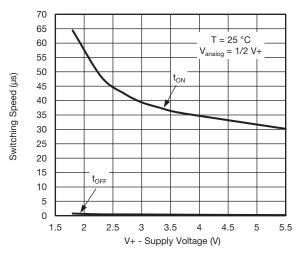
Switching Threshold vs. Supply Voltage



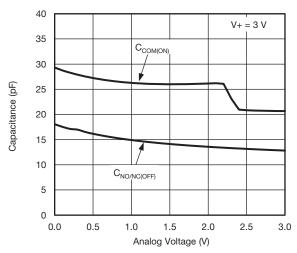
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Charge Injection vs. Analog Voltage



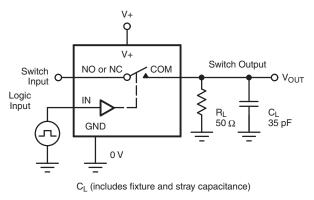
Switching Time vs. Supply Voltage



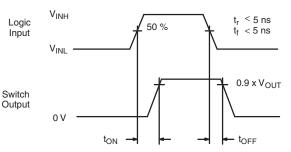
Capacitance vs. Analog Voltage



TEST CIRCUITS



$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$



Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

Fig. 1 - Switching Time

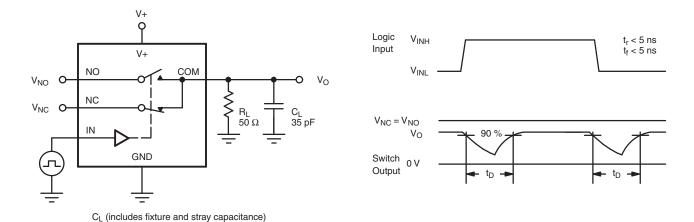


Fig. 2 - Break-Before-Make Interval

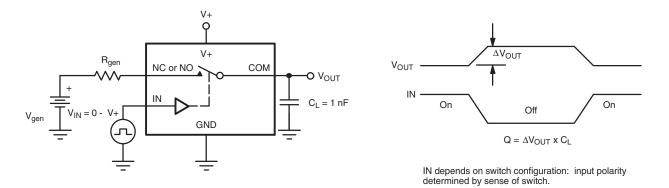


Fig. 3 - Charge Injection

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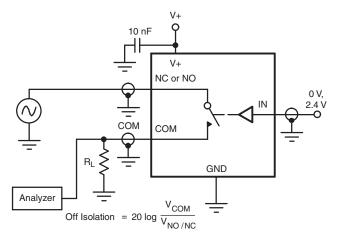


Fig. 4 - Off-Isolation

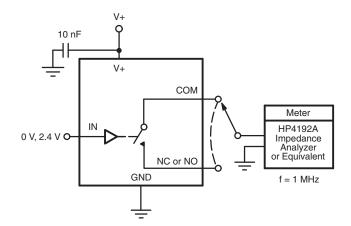


Fig. 5 - Channel Off / On Capacitance

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